

# NST45010MW6T1G

## Dual Matched General Purpose Transistor

### PNP Matched Pair

These transistors are housed in an ultra-small SOT-363 package ideally suited for portable products. They are assembled to create a pair of devices highly matched in all parameters, eliminating the need for costly trimming. Applications are Current Mirrors; Differential, Sense and Balanced Amplifiers; Mixers; Detectors and Limiters. Complementary NPN equivalent NST45011MW6T1G is available.

#### Features

- Current Gain Matching to 10%
- Base-Emitter Voltage Matched to  $\leq 2$  mV
- Drop-In Replacement for Standard Device
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	-45	V
Collector-Base Voltage	$V_{CBO}$	-50	V
Emitter-Base Voltage	$V_{EBO}$	-5.0	V
Collector Current - Continuous	$I_C$	-100	mAdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### THERMAL CHARACTERISTICS

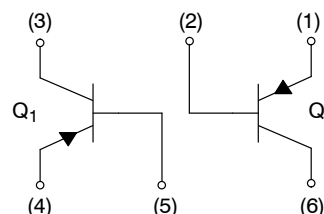
Characteristic	Symbol	Max	Unit
Total Device Dissipation Per Device FR-5 Board (Note 1) $T_A = 25^\circ\text{C}$ Derate Above $25^\circ\text{C}$	$P_D$	380 250	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	328	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

1. FR-5 = 1.0 x 0.75 x 0.062 in.



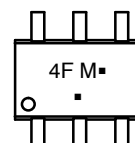
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SOT-363  
CASE 419B  
STYLE 1

#### MARKING DIAGRAMS



4F = Device Code  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

Device	Package	Shipping†
NST45010MW6T1G	SOT-363 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NST45010MW6T1G

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector - Emitter Breakdown Voltage, (I <sub>C</sub> = -10 mA)	V <sub>(BR)CEO</sub>	-45	-	-	V
Collector - Emitter Breakdown Voltage, (I <sub>C</sub> = -10 μA, V <sub>EB</sub> = 0)	V <sub>(BR)CES</sub>	-50	-	-	V
Collector - Base Breakdown Voltage, (I <sub>C</sub> = -10 μA)	V <sub>(BR)CBO</sub>	-50	-	-	V
Emitter - Base Breakdown Voltage, (I <sub>E</sub> = -1.0 μA)	V <sub>(BR)EBO</sub>	-5.0	-	-	V
Collector Cutoff Current (V <sub>CB</sub> = -30 V) (V <sub>CB</sub> = -30 V, T <sub>A</sub> = 150°C)	I <sub>CBO</sub>	-	-	-15 -5.0	nA μA

## ON CHARACTERISTICS

DC Current Gain (I <sub>C</sub> = -10 μA, V <sub>CE</sub> = -5.0 V) (I <sub>C</sub> = -2.0 mA, V <sub>CE</sub> = -5.0 V) (I <sub>C</sub> = -2.0 mA, V <sub>CE</sub> = -5.0 V) (Note 2)	h <sub>FE</sub>  h <sub>FE(1)1</sub> /h <sub>FE(2)1</sub>	- 220 0.9	150 290 1.0	- 475 1.1	-
Collector - Emitter Saturation Voltage (I <sub>C</sub> = -10 mA, I <sub>B</sub> = -0.5 mA) (I <sub>C</sub> = -100 mA, I <sub>B</sub> = -5.0 mA)	V <sub>CE(sat)</sub>	- -	- -	-300 -650	mV
Base - Emitter Saturation Voltage (I <sub>C</sub> = -10 mA, I <sub>B</sub> = -0.5 mA) (I <sub>C</sub> = -100 mA, I <sub>B</sub> = -5.0 mA)	V <sub>BE(sat)</sub>	- -	-700 -900	- -	mV
Base - Emitter On Voltage (I <sub>C</sub> = -2.0 mA, V <sub>CE</sub> = -5.0 V) (I <sub>C</sub> = -10 mA, V <sub>CE</sub> = -5.0 V) (I <sub>C</sub> = -2.0 mA, V <sub>CE</sub> = -5.0 V) (Note 3)	V <sub>BE(on)</sub>  V <sub>BE(1)1</sub> - V <sub>BE(2)1</sub>	-600 - -	- - -1.0	-750 -820 -2.0	mV

## SMALL-SIGNAL CHARACTERISTICS

Current - Gain - Bandwidth Product, (I <sub>C</sub> = -10 mA, V <sub>CE</sub> = -5 Vdc, f = 100 MHz)	f <sub>T</sub>	100	-	-	MHz
Output Capacitance, (V <sub>CB</sub> = -10 V, f = 1.0 MHz)	C <sub>ob</sub>	-	-	4.5	pF
Noise Figure, (I <sub>C</sub> = -0.2 mA, V <sub>CE</sub> = -5 Vdc, R <sub>S</sub> = 2 kΩ, f = 1 kHz, BW = 200Hz)	NF	-	-	10	dB

2. h<sub>FE(1)1</sub>/h<sub>FE(2)1</sub> is the ratio of one transistor compared to the other transistor within the same package. The smaller h<sub>FE</sub> is used as numerator.
3. V<sub>BE(1)1</sub> - V<sub>BE(2)1</sub> is the absolute difference of one transistor compared to the other transistor within the same package.

# NST45010MW6T1G

## TYPICAL CHARACTERISTICS

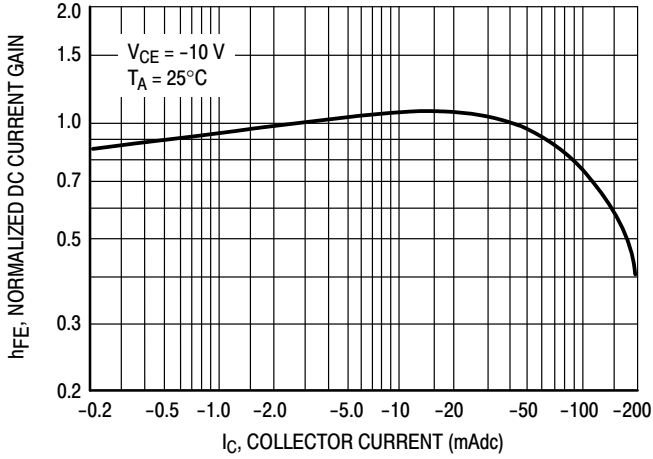


Figure 1. Normalized DC Current Gain

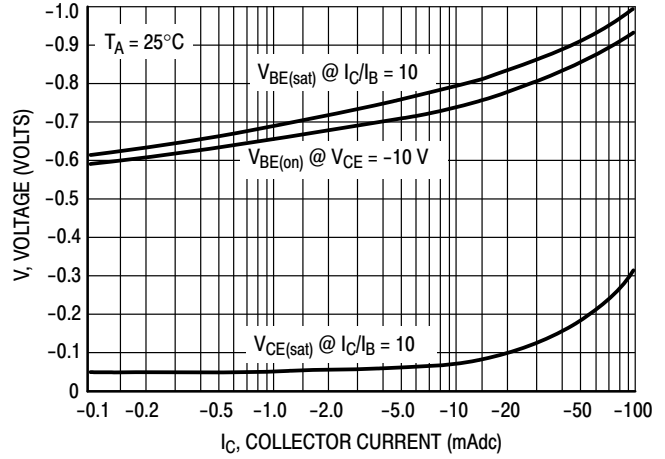


Figure 2. "Saturation" and "On" Voltages

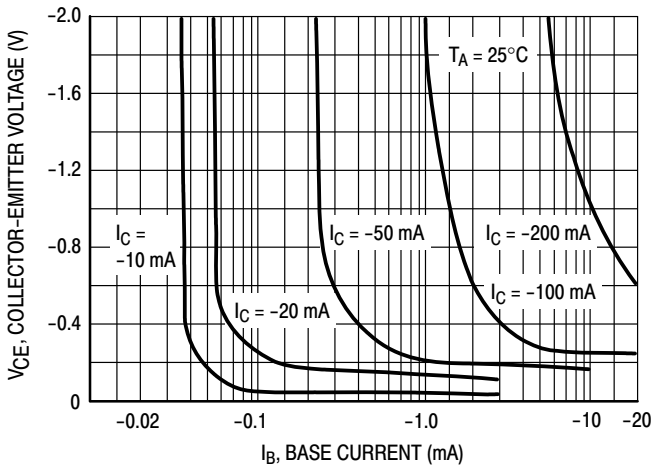


Figure 3. Collector Saturation Region

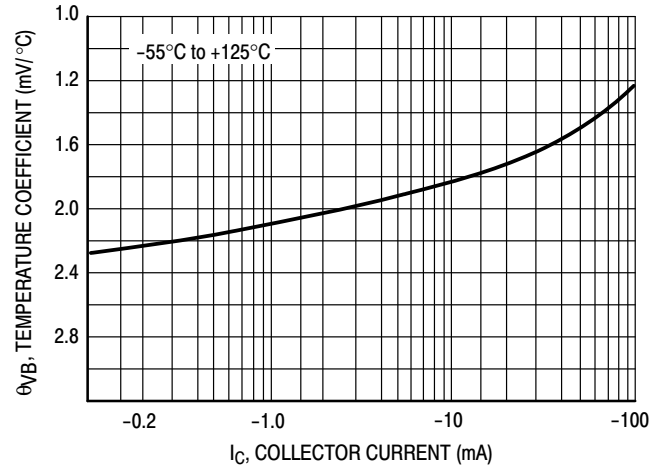


Figure 4. Base-Emitter Temperature Coefficient

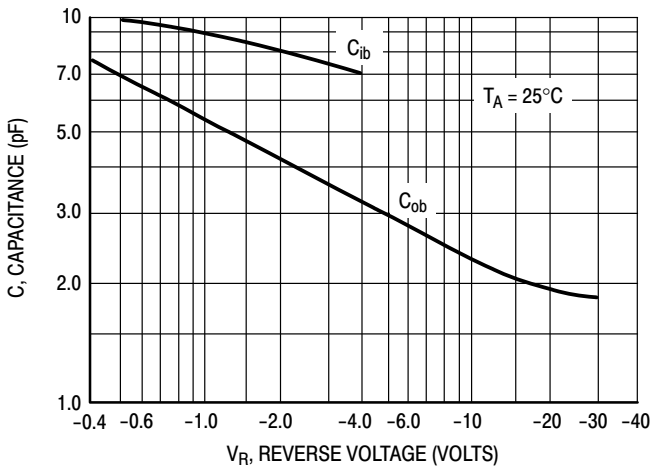


Figure 5. Capacitances

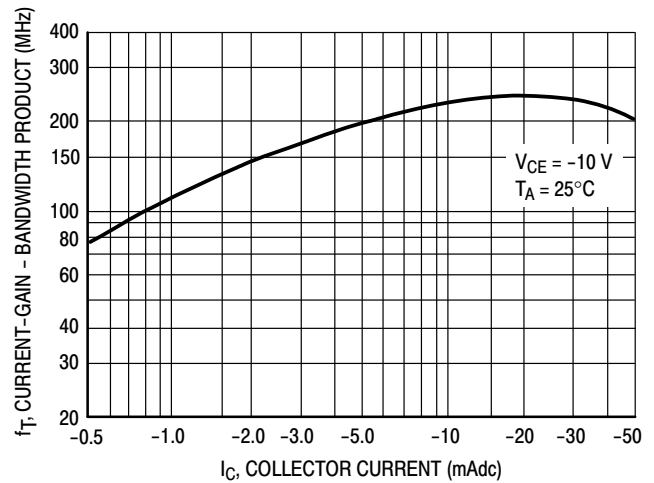


Figure 6. Current-Gain - Bandwidth Product

# NST45010MW6T1G

## TYPICAL CHARACTERISTICS

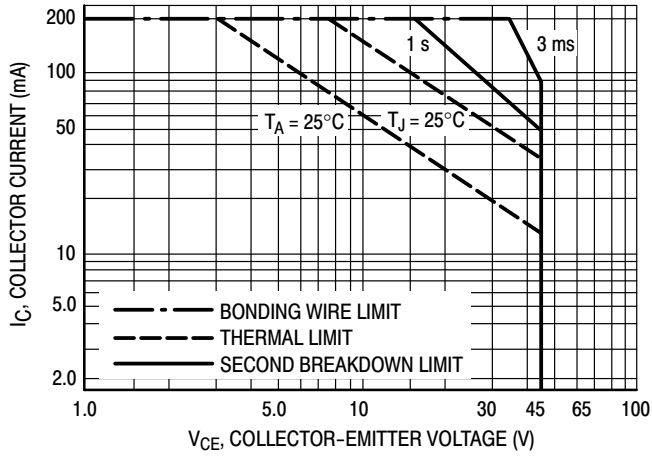


Figure 7. Active Region Safe Operating Area

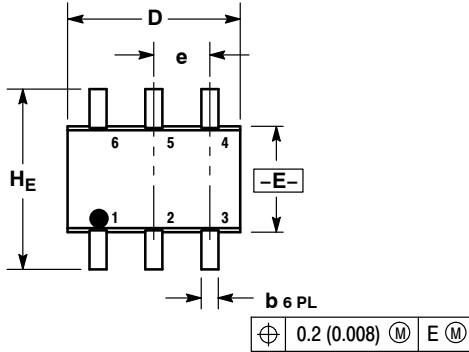
The safe operating area curves indicate  $I_C$ - $V_{CE}$  limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 7 is based upon  $T_{J(pk)} = 150^\circ\text{C}$ ;  $T_C$  or  $T_A$  is variable depending upon conditions.

# NST45010MW6T1G

## PACKAGE DIMENSIONS

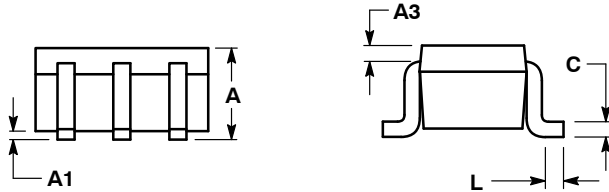
SC-88 (SOT-363)  
CASE 419B-02  
ISSUE W



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

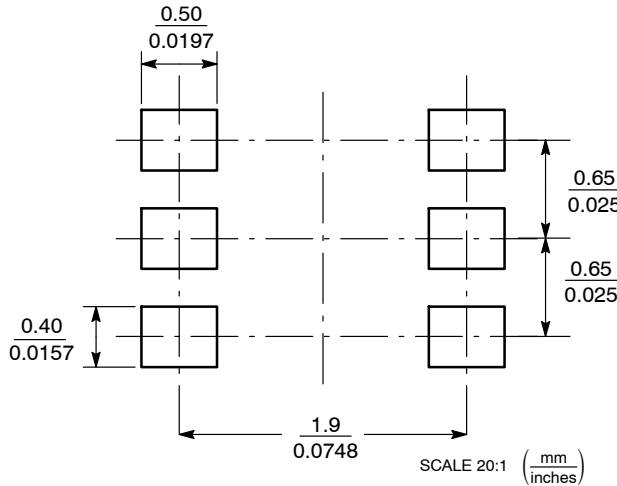
DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.20 REF			0.008 REF		
b	0.10	0.21	0.30	0.004	0.008	0.012
C	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
E	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	2.00	2.10	2.20	0.078	0.082	0.086



STYLE 1:

- PIN 1. EMITTER 2
2. BASE 2
3. COLLECTOR 1
4. EMITTER 1
5. BASE 1
6. COLLECTOR 2

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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